Yoshiro Hirayama

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/8444462/publications.pdf

Version: 2024-02-01



#	Article	IF	CITATIONS
1	Coherent Manipulation of Electronic States in a Double Quantum Dot. Physical Review Letters, 2003, 91, 226804.	2.9	679
2	Allowed and forbidden transitions in artificial hydrogen and helium atoms. Nature, 2002, 419, 278-281.	13.7	342
3	Bidirectional Counting of Single Electrons. Science, 2006, 312, 1634-1636.	6.0	323
4	Controlled multiple quantum coherences of nuclear spins in a nanometre-scale device. Nature, 2005, 434, 1001-1005.	13.7	186
5	Electrically Controlled Nuclear Spin Polarization and Relaxation by Quantum-Hall States. Physical Review Letters, 2002, 88, 176601.	2.9	146
6	Quantum Hall Transition in Real Space: From Localized to Extended States. Physical Review Letters, 2008, 101, 256802.	2.9	132
7	Valley Polarization in Si(100) at Zero Magnetic Field. Physical Review Letters, 2006, 96, 236801.	2.9	131
8	Imaging of Friedel Oscillation Patterns of Two-Dimensionally Accumulated Electrons at Epitaxially Grown InAs(111)ASurfaces. Physical Review Letters, 2001, 86, 3384-3387.	2.9	122
9	Electron counting of single-electron tunneling current. Applied Physics Letters, 2004, 84, 2343-2345.	1.5	114
10	Fabrication of a GaAs quantum-well-wire structure by Ga focused-ion-beam implantation and its optical properties. Physical Review B, 1988, 37, 2774-2777.	1.1	107
11	Resonant tunneling through one- and zero-dimensional states constricted byAlxGa1â^`xAs/GaAs/AlxGa1â^`xAs heterojunctions and high-resistance regions induced by focused Ga ion-beam implanation. Physical Review B, 1990, 41, 5459-5462.	1.1	103
12	Ion-Species Dependence of Interdiffusion in Ion-Implanted GaAs-AlAs Superlattices. Japanese Journal of Applied Physics, 1985, 24, 1498-1502.	0.8	102
13	Measurement of the Noise Spectrum Using a Multiple-Pulse Sequence. Physical Review Letters, 2011, 107, 170504.	2.9	89
14	Negative Coulomb Drag in a One-Dimensional Wire. Science, 2006, 313, 204-207.	6.0	87
15	Compositional Disordering of GaAs-AlxGa1-xAs Superlattice by Ga Focused Ion Beam Implantation and its Application to Submicron Structure Fabrication. Japanese Journal of Applied Physics, 1985, 24, L516-L518.	0.8	85
16	Charge noise analysis of an AlGaAs/GaAs quantum dot using transmission-type radio-frequency single-electron transistor technique. Applied Physics Letters, 2000, 77, 543-545.	1.5	75
17	Charge Excitations in Easy-Axis and Easy-Plane Quantum Hall Ferromagnets. Physical Review Letters, 2001, 87, 196801.	2.9	65
18	Rotation and phase-shift operations for a charge qubit in a double quantum dot. Physica E: Low-Dimensional Systems and Nanostructures. 2004. 21, 1046-1052.	1.3	65

Yoshiro Hirayama

#	Article	IF	CITATIONS
19	Electronic transport through very short and narrow channels constricted in GaAs by highly resistive Ga-implanted regions. Physical Review B, 1989, 39, 5535-5537.	1.1	64
20	Two-dimensional growth of InSb thin films on GaAs(111)A substrates. Applied Physics Letters, 2000, 76, 589-591.	1.5	61
21	Nonequilibrium Transport through a Vertical Quantum Dot in the Absence of Spin-Flip Energy Relaxation. Physical Review Letters, 2002, 88, 236802.	2.9	57
22	High Electron Mobility in AlGaAs/GaAs Modulation-Doped Structures. Japanese Journal of Applied Physics, 1991, 30, 902-905.	0.8	54
23	Low-Frequency Spin Dynamics in a Canted Antiferromagnet. Science, 2006, 313, 329-332.	6.0	50
24	Optical probing of composite fermions in a two-dimensional electron gas. Nature Physics, 2006, 2, 239-243.	6.5	48
25	Interdiffusion of Al and Ga in Si-Implanted GaAs–AlAs Superlattices. Japanese Journal of Applied Physics, 1984, 23, 1568-1572.	0.8	45
26	Electrical Properties of Ga Ion Beam Implanted GaAs Epilayer. Japanese Journal of Applied Physics, 1985, 24, L965-L967.	0.8	44
27	Ballistic electron transport in macroscopic fourâ€ŧerminal square structures with high mobility. Applied Physics Letters, 1991, 58, 2672-2674.	1.5	44
28	Local Density of States in Zero-Dimensional Semiconductor Structures. Physical Review Letters, 2001, 87, 196804.	2.9	43
29	Two-dimensional electron gas formed in a back-gated undoped heterostructure. Applied Physics Letters, 1998, 72, 1745-1747.	1.5	41
30	Conductance characteristics of ballistic oneâ€dimensional channels controlled by a gate electrode. Applied Physics Letters, 1989, 54, 2556-2558.	1.5	36
31	Transport characteristics of AlGaAs/GaAs wires fabricated by focused Gaâ€ionâ€beam implantation. Journal of Applied Physics, 1991, 69, 3633-3640.	1.1	33
32	Resonant tunneling of three-dimensional electrons into degenerate zero-dimensional levels. Physical Review B, 1991, 44, 13815-13818.	1.1	30
33	Robust Nodal Structure of Landau Level Wave Functions Revealed by Fourier Transform Scanning Tunneling Spectroscopy. Physical Review Letters, 2012, 109, 116805.	2.9	27
34	Nanometre-scale nuclear-spin device for quantum information processing. Journal of Physics Condensed Matter, 2006, 18, S885-S900.	0.7	25
35	Detection and Control of Spin-Orbit Interactions in a GaAs Hole Quantum Point Contact. Physical Review Letters, 2017, 118, 146801.	2.9	18
36	Transport characteristics of InSb trench-type in-plane gate quantum point contact. Applied Physics Letters, 2018, 112, .	1.5	17

Yoshiro Hirayama

#	Article	IF	CITATIONS
37	Electric Field Induced Nuclear Spin Resonance Mediated by Oscillating Electron Spin Domains in GaAs-Based Semiconductors. Physical Review Letters, 2008, 101, 137602.	2.9	11
38	Wigner solids of domain wall skyrmions. Nature Communications, 2021, 12, 6006.	5.8	10
39	Inelastic Electron Transport and Ortho–Para Fluctuation of Water Molecule in H ₂ 0@C ₆₀ Single Molecule Transistors. Nano Letters, 2021, 21, 10346-10353.	4.5	9
40	Low-Frequency Spin Fluctuations in Skyrmions Confined by Wires: Measurements of Local Nuclear Spin Relaxation. Physical Review Letters, 2011, 107, 126807.	2.9	8
41	Impact of Valley Polarization on the Resistivity in Two Dimensions. Physical Review Letters, 2011, 106, 196403.	2.9	8
42	Fabry-Pérot interference in a triple-gated quantum point contact. Applied Physics Letters, 2016, 109, 143509.	1.5	6
43	Electric-field-induced two-dimensional hole gas in undoped GaSb quantum wells. Applied Physics Letters, 2019, 114, .	1.5	6
44	Probing strain modulation in a gate-defined one-dimensional electron system. Physical Review B, 2019, 100, .	1.1	6
45	Resistively detected NMR in a triple-gate quantum point contact: Magnetic field dependence. Physical Review B, 2020, 101, .	1.1	5
46	Comparison of nuclear electric resonance and nuclear magnetic resonance in integer and fractional quantum Hall states. AIP Advances, 2015, 5, 087156.	0.6	4
47	Localized NMR Mediated by Electrical-Field-Induced Domain Wall Oscillation in Quantum-Hall-Ferromagnet Nanowire. Nano Letters, 2016, 16, 1596-1601.	4.5	4
48	Even-denominator fractional quantum Hall state in conventional triple-gated quantum point contact. Applied Physics Express, 2022, 15, 025002.	1.1	4
49	Scanning nuclear electric resonance microscopy using quantum-Hall-effect breakdown. AIP Advances, 2016, 6, 075024.	0.6	3
50	Large Zeeman Splitting in Out-of-Plane Magnetic Field in a Double-Layer Quantum Point Contact. Journal of the Physical Society of Japan, 2021, 90, 024709.	0.7	2
51	Double nuclear spin relaxation in hybrid quantum Hall systems. Physical Review B, 2021, 104, .	1.1	2
52	Quantum point contact potential curvature under correlated disorder potentials. Physical Review B, 2020, 102, .	1.1	1
53	Magnetotransport of electrically induced two-dimensional hole gases in undoped GaSb quantum wells. Physical Review Research, 2020, 2, .	1.3	1
54	Imaging disorder-induced scattering centers in quantum Hall incompressible strip. Physical Review B, 2021, 103, .	1.1	0

#	Article	IF	CITATIONS
55	Resistively Detected NMR Lineshapes in a Local Filling ν<1 Quantum Hall Breakdown. Physica Status Solidi (B): Basic Research, 2022, 259, 2100504.	0.7	0